

LNJ717W83RAS

Surface Mounting Chip LED

TSS Tri-Color Type

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

• Blue

Parameter	Symbol	Rating	Unit
Power dissipation	P_D	65	mW
Forward current	I_F	15	mA
Pulse forward current *	I_{FP}	50	mA
Reverse direct current	I_{RDC}	100	mA
Operating ambient temperature	T_{opr}	-30 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +100	$^\circ\text{C}$

Note) *: The condition of I_{FP} is duty 10%, Pulse width 1 msec.

• Pure Green

Parameter	Symbol	Rating	Unit
Power dissipation	P_D	65	mW
Forward current	I_F	15	mA
Pulse forward current *	I_{FP}	50	mA
Reverse direct current	I_{RDC}	100	mA
Operating ambient temperature	T_{opr}	-30 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +100	$^\circ\text{C}$

Note) *: The condition of I_{FP} is duty 10%, Pulse width 1 msec.

• Orange

Parameter	Symbol	Rating	Unit
Power dissipation	P_D	70	mW
Forward current	I_F	20	mA
Pulse forward current *	I_{FP}	60	mA
Reverse voltage	V_R	4	V
Operating ambient temperature	T_{opr}	-30 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +100	$^\circ\text{C}$

Note) *: The condition of I_{FP} is duty 10%, Pulse width 1 msec.

■ Electro-Optical Characteristics $T_a = 25^\circ\text{C}$

• Blue

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Luminous intensity	I_O		15	35	60	mcd
Forward current	I_F			5		mA
Forward voltage	V_F	$I_F = 5 \text{ mA}$		3.1	3.7	V
Peak emission wavelength	λ_p	$I_F = 5 \text{ mA}$		470		nm
Spectral half band width	$\Delta\lambda$	$I_F = 5 \text{ mA}$		30		nm

■ Lighting Color / Lens Color

- Blue / White Diffused
- Pure Green / White Diffused
- Orange / White Diffused

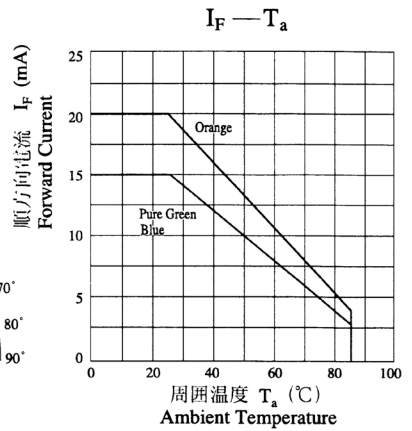
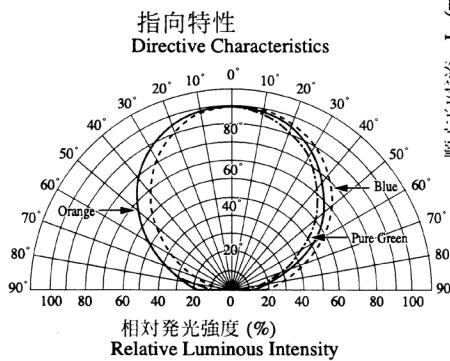
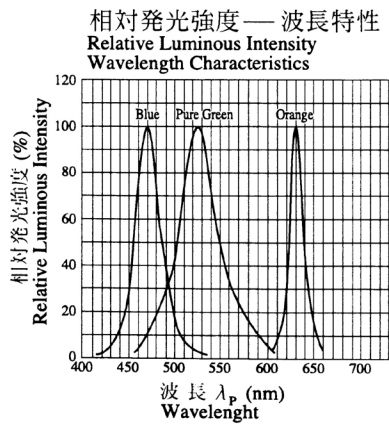
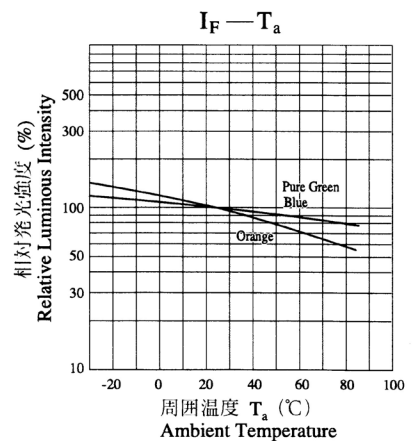
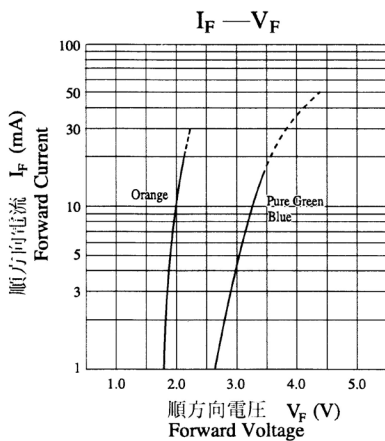
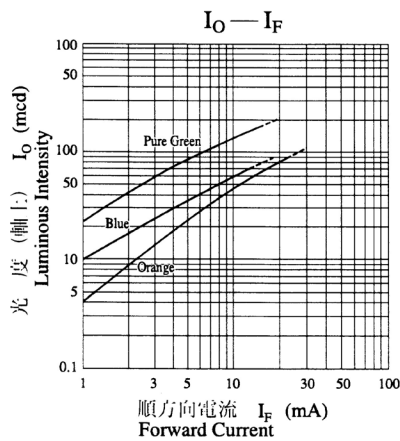
■ Electro-Optical Characteristics (Continued) $T_a = 25^\circ\text{C}$

• Pure Green

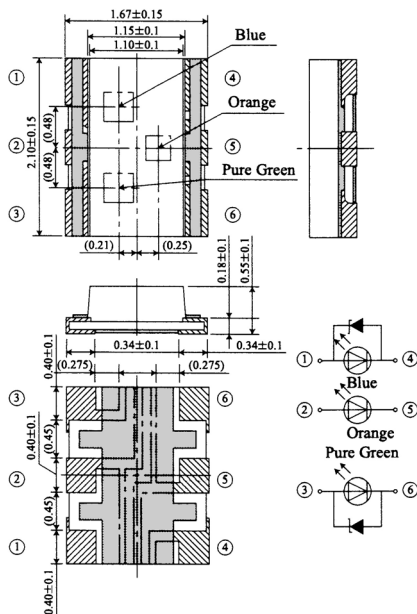
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Luminous intensity	I_O		60	90	160	mcd
Forward current	I_F			5		mA
Forward voltage	V_F	$I_F = 5\text{ mA}$		3.1	3.7	V
Peak emission wavelength	λ_p	$I_F = 5\text{ mA}$		525		nm
Spectral half band width	$\Delta\lambda$	$I_F = 5\text{ mA}$		45		nm

• Orange

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Luminous intensity	I_O		20	45	80	mcd
Forward current	I_F			10		mA
Forward voltage	V_F	$I_F = 10\text{ mA}$		2.0	2.5	V
Peak emission wavelength	λ_p	$I_F = 10\text{ mA}$		630		nm
Spectral half band width	$\Delta\lambda$	$I_F = 10\text{ mA}$		15		nm
Reverse current	I_R	$V_R = 4\text{ V}$			100	μA



■ Package (Unit: mm)



• Pin name

- 1, 2, 3: Anode
- 4, 5, 6: Cathode

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